Reason for Change: Date Code Identification Effect of Change on Product Fit, Form, or Function Refe Acq Acq Fab New S Obs Cos Nan Non Rev Pro Des Pac	PRODUCT CHANGE NOTIFIC 10077 Chip Efficiency & Brightness Improvement datasheet is updated due to increased LED brightness on the Research output is increased. 679-RK (High Bright) shipped AFTER 08/25/2020 (Date Code: will have new brightness binnning emains Unchanged, Form: Remains Unchanged, Function: Un	Red LED. LED light	Date of Issue: PCN Effective Date:	2020/08/26
Title of Change: Change Description: Reason for Change: Date Code Identification Effect of Change on Product Fit, Form, or Function Refe Acq Fab New S Cos Nan Non Rev Pro Des Pac	Chip Efficiency & Brightness Improvement latasheet is updated due to increased LED brightness on the R the chip performance and efficiency improved over the year, I output is increased. 679-RK (High Bright) shipped AFTER 08/25/2020 (Date Code: will have new brightness binnning	LED light 200825)	PCN Effective Date:	
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Date Code Identification Effect of Change on Product Fit, Form, or Function Refe Acq Fab New S Obs Cos Nan Non Rev Pro Des Pac	output is increased. 679-RK (High Bright) shipped AFTER 08/25/2020 (Date Code: will have new brightness binnning	200825)		
Identification Effect of Change on Product Fit, Form, or Function Refe Acq Acq Fab New S Obs Cos Nan Non Reve Pro Des	will have new brightness binnning			
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■ Acq ■ Acq ■ Fab New S ■ Obs ■ Cos ■ Nan ■ Non ■ Rev ■ Pro ■ Des ■ Pac				
■ Acq ■ Acq ■ Fab New S ■ Obs ■ Cos ■ Nan ■ Non ■ Rev ■ Pro ■ Des ■ Pac	rence To Change Types:			
■ Obs ■ Cos ■ Nan ■ Non ■ Rev ■ Pro ■ Des ■ Pac	uisition (Complete) uisition (Partial) rication Site Change / Qualification / Country of Origin /			
■ Nan ■ Non ■ Rev ■ Pro ■ Des ■ Pac ■ Sto	Subcontractor olescence metic Change			
■ Rev ■ Pro ■ Des ■ Pac ■ Stor	le Change nenclature Change			
■ Des ■ Pac ■ Stor				
■ Pac ■ Stor	cess Change			
■ Sto	gn Change / Data Sheet Spec Change			
	kaging and Media			
■ Log	age and Handling			
	istics			
■ Roa	·			
	lity Alert Notifications			
	iple Types			
	ronmental Announcement			
■ Oth	ronmental Announcement Component or Raw Material Added			
	ronmental Announcement Component or Raw Material Added			Revision

	AFFECTED PARTS NUMBERS								
MPN	Part Name	Replacement Part Number (if any)							
QBLP679-RK (High Bright)	LED RED 6PLCC SMD	(ii diny)							
() ()									
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	_								
	_								
	_								
	_								
	_								
	_								

Datasheet Version

Old New V2.0 V2.1

Old

Electrical / Optical Characteristic (Ta=25 °C)

Liectrical / Optical Characteristic (1a-25 C)									
Product	Color	I₅ (mA)*	(m A)* V _F (V)			λ _D (nm)	I _V (mcd)		
Froduct	Color	IF (IIIA)	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.
QBLP679-RK (High Bright)	Red	60	2.0	2.5	620	625	635	1000	1800
*Total forward current fo	r three dies	3							

Absolute Maximum Rating									
Material	P _d (mW)	I _F (mA)	I _{FP} (mA)*	V _R (V)	T _{OP} (°C)	T _{ST} (°C)	T _{SOL} (°C)**	ESD (V)	
AllnGaP	216	90	125	5	-40 ~ +80	-40 ~ +85	260	HBM 8000	

^{*}Duty 1/8 @ 1KHz **IR Reflow for no more than 10 sec @ 260 °C

Forward Voltage V- @ I-=60m/

Forward Voltage V _F @ I _F =60IIIA								
Bin	Min.	Max.	Unit					
	1.7	2.5	V					

Dominant Wavel	ength λ _D @ I _F =60m	ıA
Bin	Min.	Max.

Bin	Min.	Max.	Unit
С	620	625	
D	625	630	nm
E	630	635	

ı	Lumir	nous	Intensi	ty I	∨ for	Red @	20, I _F ∶	=60mA	

Edillillous	annious intensity if for itea to it count								
Bin	Min.	Max.	Unit						
15	1000	1300							
16	1300	1700	mcd						
17	1700	2200							

New

Electrical / Optical Characteristic (Ta=25 °C)

Product	Color	I₅ (mA)*	V- (\(\O\) \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \					l _V (mcd)		
Froduct	Color	IF (IIIA)	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	
QBLP679-RK (High Bright)	Red	60	2.0	2.5	620	625	635	1300	2000	
*Total forward current fo	r three dies					-				

Absolute Maximum Rating

Absolute Maximum Ruting									
Material	P _d (mW)	I _F (mA)	I _{FP} (mA)*	V _R (V)	T _{OP} (°C)	T _{ST} (°C)	T _{SOL} (°C)**	ESD (V)	
AllnGaP	216	90	125	5	-40 ~ +80	-40 ~ +85	260	HBM 8000	

^{*}Duty 1/8 @ 1KHz
**IR Reflow for no more than 10 sec @ 260 °C

Forward Voltage V_F @ I_F=60mA

Bin	Min.	Max.	Unit
	1.7	2.5	V

Dominant Wavelength λ_D @ I_F=60mA

Bin	Min.	Max.	Unit
C	620	625	
D	625	630	nm
E	630	635	

Luminous Intensity Iv for Red @ I_F=60mA

	Edillinous mitoria	Sity Will House if Colling				
	Din	Min	Mov	Limit		
- [DIN	IVIII.	IVIAX.	UTIIL		
1	16	1300	1700	mcd		
1	17	1700	2200			
1	18	2200	3200			